

# 3.3 V LVTTTL/LVCMOS to Differential LVPECL Translator

## MC100LVELT20

### Description

The MC100LVELT20 is a 3.3 V TTL/CMOS to differential PECL translator. Because PECL (Positive ECL) levels are used, only + 3.3 V and ground are required. The small outline SOIC-8 package and the single gate of the MC100LVELT20 makes it ideal for those applications where space, performance, and low power are at a premium.

The 100 Series contains temperature compensation.

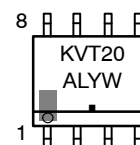
### Features

- 390 ps Typical Propagation Delay
- Maximum Input Clock Frequency > 0.8 GHz Typical
- Operating Range  $V_{CC} = 3.0\text{ V}$  to  $3.6\text{ V}$  with  $GND = 0\text{ V}$
- PNP TTL Input for Minimal Loading
- Q Output will Default HIGH with Input Open
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



SOIC-8 NB  
D SUFFIX  
CASE 751-07

### MARKING DIAGRAM



A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

\*For additional marking information, refer to Application Note [AND8002/D](#).

### ORDERING INFORMATION

| Device           | Package                | Shipping <sup>†</sup> |
|------------------|------------------------|-----------------------|
| MC100LVELT20DR2G | SOIC-8 NB<br>(Pb-Free) | 2500/Tape & Reel      |

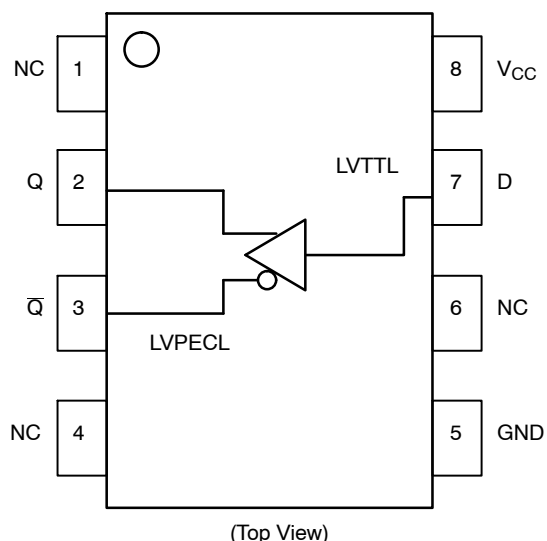
### DISCONTINUED (Note 1)

|                |                        |               |
|----------------|------------------------|---------------|
| MC100LVELT20DG | SOIC-8 NB<br>(Pb-Free) | 98 Units/Tube |
|----------------|------------------------|---------------|

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

1. **DISCONTINUED:** This device is not available. Please contact your onsemi representative for information. The most current information on this device may be available on [www.onsemi.com](http://www.onsemi.com).

# MC100LVELT20



**Figure 1. 8-Lead Pinout and Logic Diagram**

**Table 1. PIN DESCRIPTION**

| Pin             | Function                  |
|-----------------|---------------------------|
| Q, $\bar{Q}$    | Differential PECL Outputs |
| D               | LVVTTL Input              |
| V <sub>CC</sub> | Positive Supply           |
| GND             | Ground                    |
| NC              | No Connect                |

**Table 2. ATTRIBUTES**

| Characteristics                                                             | Value                         |
|-----------------------------------------------------------------------------|-------------------------------|
| Internal Input Pulldown Resistor                                            | N/A                           |
| Internal Input Pullup Resistor                                              | N/A                           |
| ESD Protection<br>Human Body Model<br>Machine Model<br>Charged Device Model | > 1.5 kV<br>> 200 V<br>> 2 kV |
| Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)               | Pb-Free Pkg                   |
| SOIC-8 NB                                                                   | Level 1                       |
| Flammability Rating<br>Oxygen Index: 28 to 34                               | UL 94 V-0 @ 0.125 in          |
| Transistor Count                                                            | 150 Devices                   |
| Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test                      |                               |

1. For additional information, see Application Note [AND8003/D](#).

**Table 3. MAXIMUM RATINGS**

| Symbol           | Parameter                                | Condition 1         | Condition 2                      | Rating      | Unit |
|------------------|------------------------------------------|---------------------|----------------------------------|-------------|------|
| V <sub>CC</sub>  | Power Supply                             | GND = 0 V           |                                  | 6           | V    |
| V <sub>I</sub>   | Input Voltage                            | GND = 0 V           | V <sub>I</sub> ≤ V <sub>CC</sub> | 6           | V    |
| I <sub>out</sub> | Output Current                           | Continuous<br>Surge |                                  | 50<br>100   | mA   |
| T <sub>A</sub>   | Operating Temperature Range              |                     |                                  | -40 to +85  | °C   |
| T <sub>stg</sub> | Storage Temperature Range                |                     |                                  | -65 to +150 | °C   |
| θ <sub>JA</sub>  | Thermal Resistance (Junction-to-Ambient) | 0 lfpm<br>500 lfpm  | SOIC-8 NB                        | 190<br>130  | °C/W |
| θ <sub>JC</sub>  | Thermal Resistance (Junction-to-Case)    | Standard Board      | SOIC-8 NB                        | 41 to 44    | °C/W |
| T <sub>sol</sub> | Wave Solder (Pb-Free)                    |                     |                                  | 265         | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# MC100LVELT20

**Table 4. LVTTTL INPUT DC CHARACTERISTICS** ( $V_{CC} = 3.3\text{ V}$ ,  $GND = 0\text{ V}$ ,  $T_A = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ )

| Symbol    | Characteristic                                     | Min | Typ | Max  | Unit          |
|-----------|----------------------------------------------------|-----|-----|------|---------------|
| $I_{IH}$  | Input HIGH Current ( $V_{in} = 2.7\text{ V}$ )     |     |     | 20   | $\mu\text{A}$ |
| $I_{IHH}$ | Input HIGH Current MAX ( $V_{in} = 6.0\text{ V}$ ) |     |     | 100  | $\mu\text{A}$ |
| $I_{IL}$  | Input LOW Current ( $V_{in} = 0.5\text{ V}$ )      |     |     | -0.6 | $\text{mA}$   |
| $V_{IK}$  | Input Clamp Voltage ( $I_{in} = -18\text{ mA}$ )   |     |     | -1.2 | $\text{V}$    |
| $V_{IH}$  | Input HIGH Voltage                                 | 2.0 |     |      | $\text{V}$    |
| $V_{IL}$  | Input LOW Voltage                                  |     |     | 0.8  | $\text{V}$    |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

**Table 5. 100LVELT PECL OUTPUT DC CHARACTERISTICS** ( $V_{CC} = 3.3\text{ V}$ ,  $GND = 0\text{ V}$  (Note 1))

| Symbol   | Characteristic                | -40°C |      |      | 25°C |      |      | 85°C |      |      | Unit        |
|----------|-------------------------------|-------|------|------|------|------|------|------|------|------|-------------|
|          |                               | Min   | Typ  | Max  | Min  | Typ  | Max  | Min  | Typ  | Max  |             |
| $I_{CC}$ | Negative Power Supply Current | 20    | 25   | 30   | 22   | 27   | 32   | 23   | 28   | 33   | $\text{mA}$ |
| $V_{OH}$ | Output HIGH Voltage (Note 2)  | 2155  | 2280 | 2405 | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | $\text{mV}$ |
| $V_{OL}$ | Output LOW Voltage (Note 2)   | 1355  | 1480 | 1605 | 1355 | 1480 | 1605 | 1355 | 1480 | 1605 | $\text{mV}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Output parameters vary 1:1 with  $V_{CC}$ .
2. All loading with  $50\ \Omega$  to  $V_{CC} - 2.0\text{ V}$ .

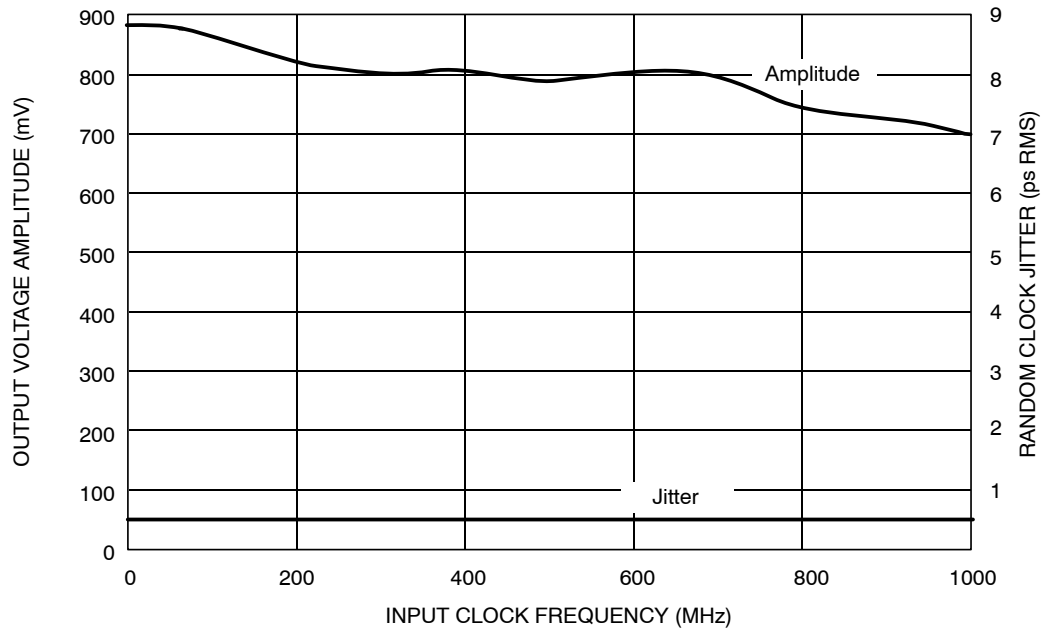
**Table 6. AC CHARACTERISTICS** ( $V_{CC} = 3.0\text{ V}$  to  $3.6\text{ V}$ ,  $GND = 0\text{ V}$  (Note 1))

| Symbol                   | Characteristic                                     | -40°C |     |     | 25°C |     |     | 85°C |     |     | Unit         |
|--------------------------|----------------------------------------------------|-------|-----|-----|------|-----|-----|------|-----|-----|--------------|
|                          |                                                    | Min   | Typ | Max | Min  | Typ | Max | Min  | Typ | Max |              |
| $f_{max}$                | Maximum Input Clock Frequency (Figure 2)           | 600   | 800 |     | 600  | 800 |     | 600  | 800 |     | $\text{MHz}$ |
| $t_{PLH}$ ,<br>$t_{PHL}$ | Propagation Delay to Output Differential           | 280   | 350 | 430 | 300  | 370 | 450 | 320  | 400 | 490 | $\text{ps}$  |
| $t_{SKEW}$               | Device-to-Device Skew (Note 2)                     |       |     | 250 |      |     | 250 |      |     | 250 | $\text{ps}$  |
| $t_{JITTER}$             | Random Clock Jitter (RMS) (Figure 2)               |       | < 1 | < 2 |      | < 1 | < 2 |      | < 1 | < 2 | $\text{ps}$  |
| $t_r$ ,<br>$t_f$         | Output Rise/Fall Times<br>Q, $\bar{Q}$ (20% – 80%) | 70    | 100 | 225 | 80   | 120 | 225 | 90   | 140 | 225 | $\text{ps}$  |

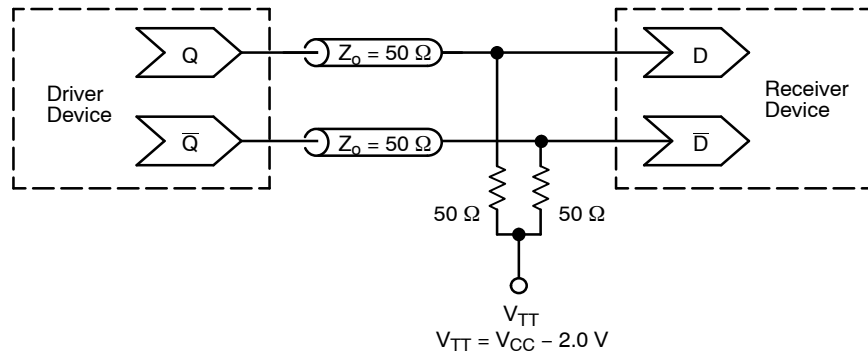
NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Measured using a LVTTTL source, 50% duty cycle clock source. All loading with  $50\ \Omega$  to  $V_{CC} - 2.0\text{ V}$ .
2. Skew is measured between outputs under identical transitions.

## MC100LVELT20



**Figure 2. Output Voltage Amplitude ( $V_{OUTpp}$ )/RMS Jitter vs. Input Clock Frequency at Ambient Temperature**



**Figure 3. Typical Termination for Output Driver and Device Evaluation**  
(See Application Note [AND8020/D](#) – Termination of ECL Logic Devices.)

## MC100LVELT20

### Resource Reference of Application Notes

- AN1405/D** – ECL Clock Distribution Techniques
- AN1406/D** – Designing with PECL (ECL at +5.0 V)
- AN1503/D** – ECLinPS™ I/O SPICE Modeling Kit
- AN1504/D** – Metastability and the ECLinPS Family
- AN1568/D** – Interfacing Between LVDS and ECL
- AN1672/D** – The ECL Translator Guide
- AND8001/D** – Odd Number Counters Design
- AND8002/D** – Marking and Date Codes
- AND8020/D** – Termination of ECL Logic Devices
- AND8066/D** – Interfacing with ECLinPS
- AND8090/D** – AC Characteristics of ECL Devices

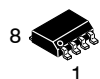
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## MC100LVELT20

### REVISION HISTORY

| Revision | Description of Changes                                                                       | Date      |
|----------|----------------------------------------------------------------------------------------------|-----------|
| 2        | MC100LVELT20DG OPN Marked as Discontinued + Rebranded the Data Sheet to <b>onsemi</b> format | 7/10/2025 |

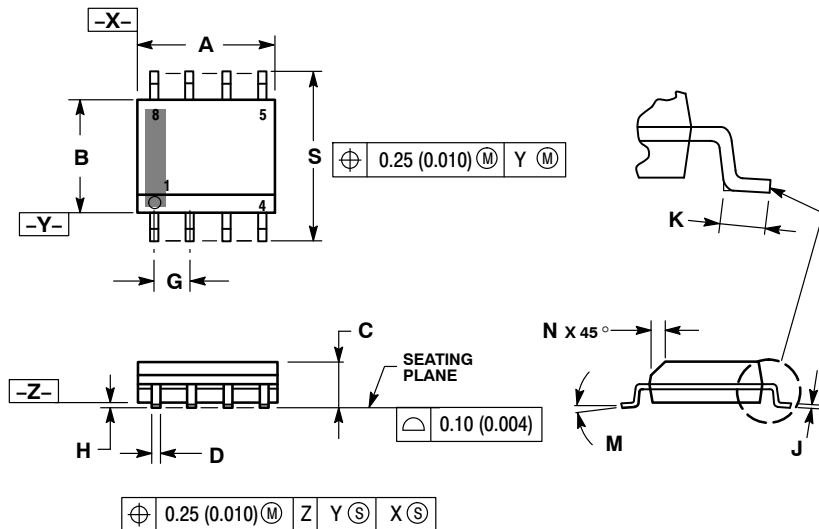
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



SCALE 1:1

SOIC-8 NB  
CASE 751-07  
ISSUE AK

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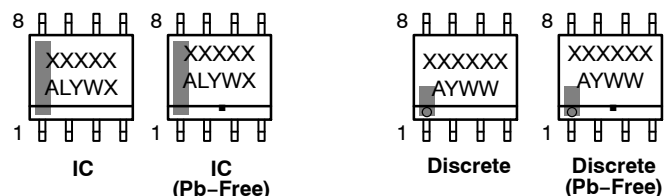
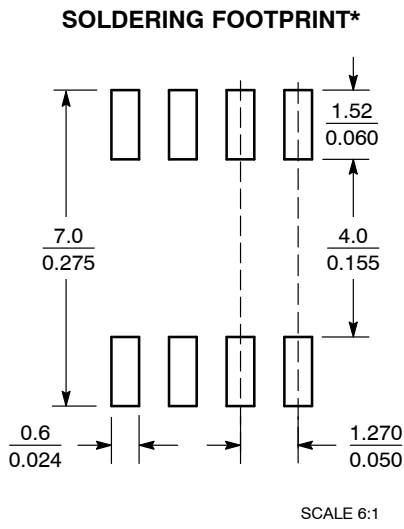


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 4.80        | 5.00 | 0.189     | 0.197 |
| B   | 3.80        | 4.00 | 0.150     | 0.157 |
| C   | 1.35        | 1.75 | 0.053     | 0.069 |
| D   | 0.33        | 0.51 | 0.013     | 0.020 |
| G   | 1.27 BSC    |      | 0.050 BSC |       |
| H   | 0.10        | 0.25 | 0.004     | 0.010 |
| J   | 0.19        | 0.25 | 0.007     | 0.010 |
| K   | 0.40        | 1.27 | 0.016     | 0.050 |
| M   | 0°          | 8°   | 0°        | 8°    |
| N   | 0.25        | 0.50 | 0.010     | 0.020 |
| S   | 5.80        | 6.20 | 0.228     | 0.244 |

GENERIC  
MARKING DIAGRAM\*



XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

|                  |             |                                                                                                                                                                                  |
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| DESCRIPTION:     | SOIC-8 NB   | PAGE 1 OF 2                                                                                                                                                                      |

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**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

DATE 16 FEB 2011

|                                                                                                                                                                                                   |                                                                                                                                                                                          |                                                                                                                                                                                    |                                                                                                                                                                                                        |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>STYLE 1:</b><br>PIN 1. EMITTER<br>2. COLLECTOR<br>3. COLLECTOR<br>4. EMITTER<br>5. EMITTER<br>6. BASE<br>7. BASE<br>8. EMITTER                                                                 | <b>STYLE 2:</b><br>PIN 1. COLLECTOR, DIE, #1<br>2. COLLECTOR, #1<br>3. COLLECTOR, #2<br>4. COLLECTOR, #2<br>5. BASE, #2<br>6. EMITTER, #2<br>7. BASE, #1<br>8. EMITTER, #1               | <b>STYLE 3:</b><br>PIN 1. DRAIN, DIE #1<br>2. DRAIN, #1<br>3. DRAIN, #2<br>4. DRAIN, #2<br>5. GATE, #2<br>6. SOURCE, #2<br>7. GATE, #1<br>8. SOURCE, #1                            | <b>STYLE 4:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE<br>4. ANODE<br>5. ANODE<br>6. ANODE<br>7. ANODE<br>8. COMMON CATHODE                                                                           |
| <b>STYLE 5:</b><br>PIN 1. DRAIN<br>2. DRAIN<br>3. DRAIN<br>4. DRAIN<br>5. GATE<br>6. GATE<br>7. SOURCE<br>8. SOURCE                                                                               | <b>STYLE 6:</b><br>PIN 1. SOURCE<br>2. DRAIN<br>3. DRAIN<br>4. SOURCE<br>5. SOURCE<br>6. GATE<br>7. GATE<br>8. SOURCE                                                                    | <b>STYLE 7:</b><br>PIN 1. INPUT<br>2. EXTERNAL BYPASS<br>3. THIRD STAGE SOURCE<br>4. GROUND<br>5. DRAIN<br>6. GATE 3<br>7. SECOND STAGE Vd<br>8. FIRST STAGE Vd                    | <b>STYLE 8:</b><br>PIN 1. COLLECTOR, DIE #1<br>2. BASE, #1<br>3. BASE, #2<br>4. COLLECTOR, #2<br>5. COLLECTOR, #2<br>6. EMITTER, #2<br>7. EMITTER, #1<br>8. COLLECTOR, #1                              |
| <b>STYLE 9:</b><br>PIN 1. EMITTER, COMMON<br>2. COLLECTOR, DIE #1<br>3. COLLECTOR, DIE #2<br>4. EMITTER, COMMON<br>5. EMITTER, COMMON<br>6. BASE, DIE #2<br>7. BASE, DIE #1<br>8. EMITTER, COMMON | <b>STYLE 10:</b><br>PIN 1. GROUND<br>2. BIAS 1<br>3. OUTPUT<br>4. GROUND<br>5. GROUND<br>6. BIAS 2<br>7. INPUT<br>8. GROUND                                                              | <b>STYLE 11:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. DRAIN 2<br>7. DRAIN 1<br>8. DRAIN 1                                               | <b>STYLE 12:</b><br>PIN 1. SOURCE<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                                 |
| <b>STYLE 13:</b><br>PIN 1. N.C.<br>2. SOURCE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                              | <b>STYLE 14:</b><br>PIN 1. N-SOURCE<br>2. N-GATE<br>3. P-SOURCE<br>4. P-GATE<br>5. P-DRAIN<br>6. P-DRAIN<br>7. N-DRAIN<br>8. N-DRAIN                                                     | <b>STYLE 15:</b><br>PIN 1. ANODE 1<br>2. ANODE 1<br>3. ANODE 1<br>4. ANODE 1<br>5. CATHODE, COMMON<br>6. CATHODE, COMMON<br>7. CATHODE, COMMON<br>8. CATHODE, COMMON               | <b>STYLE 16:</b><br>PIN 1. EMITTER, DIE #1<br>2. BASE, DIE #1<br>3. EMITTER, DIE #2<br>4. BASE, DIE #2<br>5. COLLECTOR, DIE #2<br>6. COLLECTOR, DIE #2<br>7. COLLECTOR, DIE #1<br>8. COLLECTOR, DIE #1 |
| <b>STYLE 17:</b><br>PIN 1. VCC<br>2. V2OUT<br>3. V1OUT<br>4. TXE<br>5. RXE<br>6. VEE<br>7. GND<br>8. ACC                                                                                          | <b>STYLE 18:</b><br>PIN 1. ANODE<br>2. ANODE<br>3. SOURCE<br>4. GATE<br>5. DRAIN<br>6. DRAIN<br>7. CATHODE<br>8. CATHODE                                                                 | <b>STYLE 19:</b><br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. SOURCE 2<br>4. GATE 2<br>5. DRAIN 2<br>6. MIRROR 2<br>7. DRAIN 1<br>8. MIRROR 1                                             | <b>STYLE 20:</b><br>PIN 1. SOURCE (N)<br>2. GATE (N)<br>3. SOURCE (P)<br>4. GATE (P)<br>5. DRAIN<br>6. DRAIN<br>7. DRAIN<br>8. DRAIN                                                                   |
| <b>STYLE 21:</b><br>PIN 1. CATHODE 1<br>2. CATHODE 2<br>3. CATHODE 3<br>4. CATHODE 4<br>5. CATHODE 5<br>6. COMMON ANODE<br>7. COMMON ANODE<br>8. CATHODE 6                                        | <b>STYLE 22:</b><br>PIN 1. I/O LINE 1<br>2. COMMON CATHODE/VCC<br>3. COMMON CATHODE/VCC<br>4. I/O LINE 3<br>5. COMMON ANODE/GND<br>6. I/O LINE 4<br>7. I/O LINE 5<br>8. COMMON ANODE/GND | <b>STYLE 23:</b><br>PIN 1. LINE 1 IN<br>2. COMMON ANODE/GND<br>3. COMMON ANODE/GND<br>4. LINE 2 IN<br>5. LINE 2 OUT<br>6. COMMON ANODE/GND<br>7. COMMON ANODE/GND<br>8. LINE 1 OUT | <b>STYLE 24:</b><br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR/ANODE<br>4. COLLECTOR/ANODE<br>5. CATHODE<br>6. CATHODE<br>7. COLLECTOR/ANODE<br>8. COLLECTOR/ANODE                                      |
| <b>STYLE 25:</b><br>PIN 1. VIN<br>2. N/C<br>3. REXT<br>4. GND<br>5. IOUT<br>6. IOUT<br>7. IOUT<br>8. IOUT                                                                                         | <b>STYLE 26:</b><br>PIN 1. GND<br>2. dv/dt<br>3. ENABLE<br>4. ILIMIT<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. VCC                                                                    | <b>STYLE 27:</b><br>PIN 1. ILIMIT<br>2. OVLO<br>3. UVLO<br>4. INPUT+<br>5. SOURCE<br>6. SOURCE<br>7. SOURCE<br>8. DRAIN                                                            | <b>STYLE 28:</b><br>PIN 1. SW_TO_GND<br>2. DASIC_OFF<br>3. DASIC_SW_DET<br>4. GND<br>5. V_MON<br>6. VBULK<br>7. VBULK<br>8. VIN                                                                        |
| <b>STYLE 29:</b><br>PIN 1. BASE, DIE #1<br>2. EMITTER, #1<br>3. BASE, #2<br>4. EMITTER, #2<br>5. COLLECTOR, #2<br>6. COLLECTOR, #2<br>7. COLLECTOR, #1<br>8. COLLECTOR, #1                        | <b>STYLE 30:</b><br>PIN 1. DRAIN 1<br>2. DRAIN 1<br>3. GATE 2<br>4. SOURCE 2<br>5. SOURCE 1/DRAIN 2<br>6. SOURCE 1/DRAIN 2<br>7. SOURCE 1/DRAIN 2<br>8. GATE 1                           |                                                                                                                                                                                    |                                                                                                                                                                                                        |

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| <b>DESCRIPTION:</b>     | <b>SOIC-8 NB</b>   | <b>PAGE 2 OF 2</b>                                                                                                                                                                  |

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